

Agilent MSA-0270 Cascadable Silicon Bipolar MMIC Amplifier

Data Sheet

Features

- Cascadable 50 Ω Gain Block •
- 3 dB Bandwidth: DC to 2.8 GHz
- 12.0 dB Typical Gain at 1.0 GHz
- Unconditionally Stable (k>1)
- Hermetic Gold-ceramic **Microstrip Package**

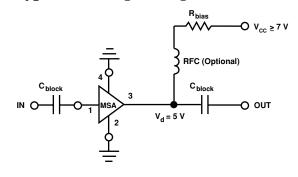
Description

The MSA-0270 is a high performance silicon bipolar Monolithic Microwave Integrated Circuit (MMIC) housed in a hermetic, high reliability package. This MMIC is designed for use as a general purpose 50 Ω gain block. Typical applications include narrow and broad band IF and RF amplifiers in industrial and military applications.

The MSA-series is fabricated using Agilent's 10 GHz fT, 25 GHz fMAX, silicon bipolar MMIC process which uses nitride self-alignment, ion implantation, and gold metallization to achieve excellent performance, uniformity and reliability. The use of an external bias resistor for temperature and current stability also allows bias flexibility.

70 mil Package

Typical Biasing Configuration







MSA-0270 Absolute Maximum Ratings

Parameter	Absolute Maximum ^[1]			
Device Current	60 mA			
Power Dissipation ^[2,3]	325 mW			
RF Input Power	+13 dBm			
Junction Temperature	200°C			
Storage Temperature	-65 to 200°C			

Thermal Resistance^[2,4]:

 $\theta_{\rm jc} = 120^{\circ}{\rm C/W}$

Notes:

- 1. Permanent damage may occur if any of these limits are exceeded.
- 2. T_{CASE} = 25° C.
- 3. Derate at 8.3 mW/°C for $T_C > 161$ °C.
- 4. The small spot size of this technique results in a higher, though more accurate determination of θ_{jc} than do alternate methods.

Symbol	Parameters and Test Conditions:	Units	Min.	Тур.	Max.	
GP	Power Gain $(S_{21} ^2)$	f = 0.1 GHz	dB	11.5	12.5	13.5
ΔG_P	Gain Flatness	f = 0.1 to 1.8 GHz	dB		±0.6	±1.0
${ m f}_{3~ m dB}$	3 dB Bandwidth		GHz		2.8	
VSWR	Input VSWR	f = 0.1 to 3.0 GHz			1.4:1	
VSWR	Output VSWR	f = 0.1 to 3.0 GHz			1.4:1	
NF	50 Ω Noise Figure	f = 1.0 GHz	dB		6.5	
$P_{1 \ dB}$	Output Power at 1 dB Gain Compression	f = 1.0 GHz	dBm		4.5	
IP3	Third Order Intercept Point	f = 1.0 GHz	dBm		17.0	
tD	Group Delay	f = 1.0 GHz	psec		125	
Vd	Device Voltage		V	4.5	5.0	5.5
dV/dT	Device Voltage Temperature Coefficient		mV/°C		-8.0	

Electrical Specifications^[1], $T_A = 25^{\circ}C$

Note:

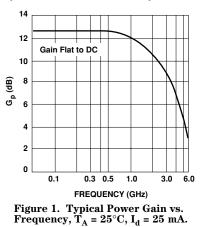
1. The recommended operating current range for this device is 18 to 40 mA. Typical performance as a function of current is on the following page.

Freq.	S ₁₁		S ₂₁		S ₁₂			S ₂₂		
GHz	Mag	Ang	dB	Mag	Ang	dB	Mag	Ang	Mag	Ang
0.1	.11	179	12.6	4.26	176	-18.4	.120	1	.12	-8
0.2	.11	174	12.6	4.24	171	-18.6	.117	3	.12	-15
0.4	.10	169	12.5	4.21	162	-18.4	.120	4	.13	-30
0.6	.09	165	12.4	4.17	154	-18.2	.123	5	.14	-44
0.8	.08	161	12.3	4.11	146	-18.2	.123	7	.14	-55
1.0	.06	161	12.2	4.05	137	-18.0	.126	9	.15	-64
1.5	.02	-150	11.7	3.85	116	-17.2	.138	11	.16	-84
2.0	.06	-110	11.1	3.57	96	-16.3	.153	11	.16	-102
2.5	.11	-112	10.3	3.27	82	-15.7	.165	14	.14	-106
3.0	.17	-134	9.3	2.92	65	-15.2	.174	12	.13	-114
3.5	.22	-147	8.2	2.56	48	-14.7	.185	6	.15	-111
4.0	.26	156	7.0	2.23	33	-14.3	.192	3	.19	-107
5.0	.28	179	4.7	1.72	8	-14.0	.199	-6	.27	-107
6.0	.30	143	3.0	1.41	-13	-13.8	.204	-14	.29	-119

MSA-0270 Typical Scattering Parameters (Z $_{0}$ = 50 Ω , T $_{A}$ = 25 °C, I $_{d}$ = 25 mA)

Typical Performance, $T_A = 25^{\circ}C$

(unless otherwise noted)



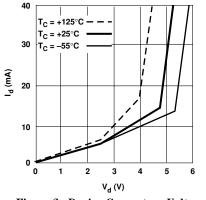
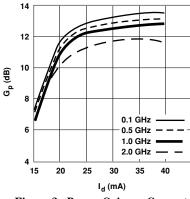


Figure 2. Device Current vs. Voltage.





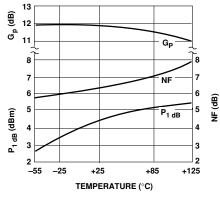


Figure 4. Output Power at 1 dB Gain Compression, NF and Power Gain vs. Mounting Surface Temperature, f = 1.0 GHz, $I_d = 25$ mA.

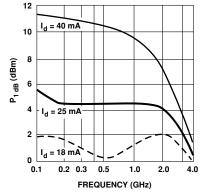
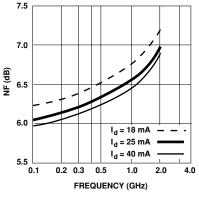


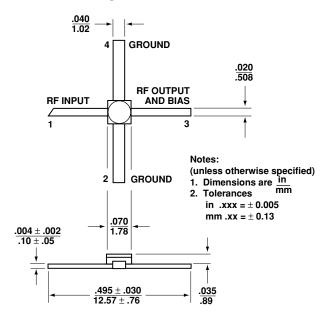
Figure 5. Output Power at 1 dB Gain Compression vs. Frequency.



Ordering Information

Part Numbers	No. of Devices	Comments		
MSA-0270	10	Bulk		

70 mil Package Dimensions



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